

SN65HVD62 AISG 开关键控同轴调制解调器收发器

1 特性

- 电源电压范围: 3V 至 5.5V
- 1.6V 至 5.5V 的独立逻辑电源
- 针对接收器的 -15dBm 至 +5dBm 的宽输入动态范围
- 可在 0dBm 至 +6dBm 范围内调节驱动器为同轴提供的功率
- 与 AISG 标准兼容的输出发射特性
- 低功耗待机模式
- 针对 RS-485 总线仲裁的方向控制
- 支持高达 115kbps 信令
- 中心频率为 2.176MHz 的集成有源带通滤波器
- 3mm × 3mm 16 引脚四方扁平无引线 (QFN) 封装

2 应用

- AISG - 针对天线线路器件的接口
- 塔顶放大器 (TMA)
- 普通调制解调器 (Modem) 接口

3 说明

这些逻辑电路 (基带) 和一个频率间的收发器调制和解调信号适用于长距离同轴介质。

HVD62 是一款集成 AISG 收发器, 此收发器的被设计成与天线接口标准组 v2.0 规范兼容。

HVD62 接收器集成了一个有源带通滤波器, 这样即使在寄生频率组件出现的时候仍然能够解调信号。此滤波器有一个 2.176MHz 的中心频率。

发射器支持介于 +0dBm 和 +6dBm 之间的可调输出功率提供给 50Ω 同轴电缆。HVD62 发射器与 AISG 标准规定的对发射频谱的要求兼容。

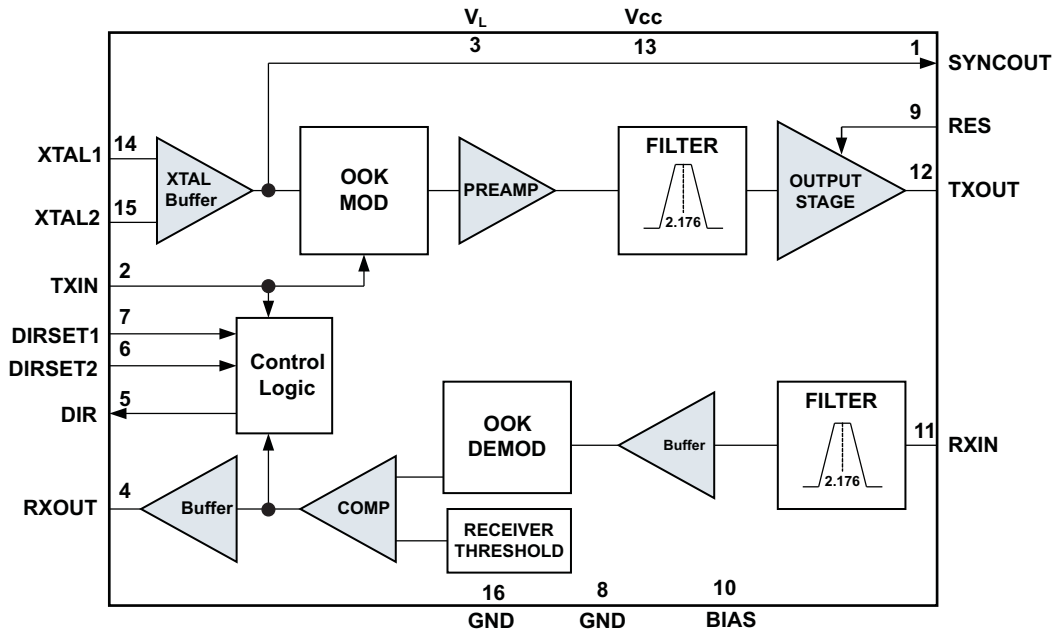
提供一个方向控制输出以使得针对一个 RS-485 接口的总线仲裁更加便捷。这些器件为晶振集成了一个振荡器, 并且接受到振荡器的标准时钟输入。

器件信息⁽¹⁾

器件型号	封装	封装尺寸 (标称值)
SN65HVD62	VQFN (16)	3.00mm x 3.00mm

(1) 要了解所有可用封装, 请见数据表末尾的可订购产品附录。

4 方框图



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5 修订历史记录

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

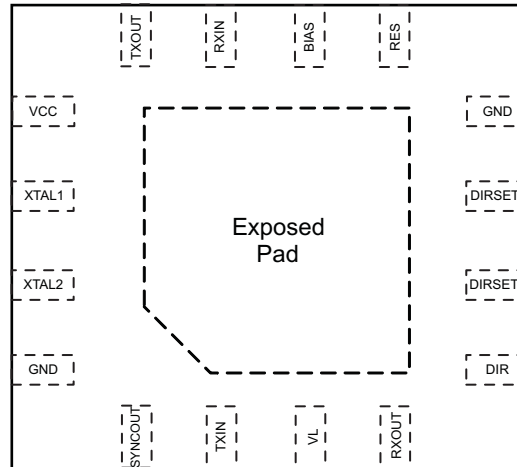
Changes from Revision B (January 2013) to Revision C	Page
• 已添加器件信息表, ESD 额定值表, 器件功能模式, 应用和实施部分, 器件和文档支持部分以及机械、封装和可订购信息部分。	1
• Moved the Storage temperature From: <i>Thermal Information</i> To: <i>Absolute Maximum Ratings</i> ⁽¹⁾	4
• Changed T _A in the <i>Recommended Operating Conditions</i> From: MAX = 85°C To: MAX = 105°C	5

Changes from Revision A (January 2012) to Revision B	Page
• 已将 <i>特性</i> “可在 +3dBm 至 +6dBm 范围内调节驱动器为同轴提供的功率”更改为“可在 0dBm 至 +6dBm 范围内调节驱动器为同轴提供的功率”	1
• Added Storage temperature to the <i>Thermal Information</i>	4
• Change the MIN value of V _{RES} in the ROC table From: 0.84 To: 0.7 V	5
• Change the TYP value of C _C in the ROC table From: 270 To: 220 nF	5
• Changed the <i>Electrical Characteristics</i>	6
• Changed the <i>Switching Characteristics</i>	7
• Added the <i>Typical Characteristics</i> section	8
• Changed the <i>Parameter Measurement Information</i> section	11
• Changed the <i>Application Information</i> section	16

Changes from Original (September 2011) to Revision A	Page
• Changed Pin 4 label (lower right) in the <i>Pin Configuration and Functions</i> diagram from TXIN to RXOUT	3
• Changed the <i>Pin Functions</i> table by merging the DESCRIPTION cells for pins 5, 6, and 7 and deleted the word DIRSET from the beginning of the second line in that description field.	3
• 已添加 rows 162 and 163 to the <i>Electrical Characteristics</i> table, under RECEIVER FILTER section	6
• 已添加 rows 210 and 211 to the <i>Switching Characteristics</i> table	7
• 已添加 表 1 和 表 2	15
• 已添加 图 22 State Transition Diagram	15

6 Pin Configuration and Functions

**RGT (VQFN) Package
16 Pins
Top View**



Pin Functions

PIN	HVD62 PIN	DESCRIPTION
	NAME	
1	SYNCOUT	Open drain output to synchronize other devices to the 4x-carrier oscillator at XTAL1,2. (8.704 MHz for HVD62)
2	TXIN	Digital data bit stream to driver.
3	VL	Logic supply voltage for the device.
4	RXOUT	Digital data bit stream from receiver.
5	DIR	DIR: Direction control output signal for bus arbitration.
6	DIRSET2	DIRSET1 and DIRSET2: Bits to set the duration of DIR
7	DIRSET1	DIRSET[2,1]:[L,L]=9.6kbps [L,H]=38.4kbps [H,L]=115kbps [H,H]=Standby Mode
8	GND	Ground
9	RES	Input voltage to adjust driver output power. Set by external resistors from BIAS pin to GND.
10	BIAS	Bias voltage output for setting driver output power by external resistors.
11	RXIN	Modulated input signal to the receiver.
12	TXOUT	Modulated output signal from the driver.
13	VCC	Analog supply voltage for the device.
14	XTAL1	Crystal oscillator's IO pins. Connect a $4 \times f_C$ crystal between these pins. Or connect XTAL1 to an 8.704 MHz clock and connect XTAL2 to GND.
15	XTAL2	
16	GND	Ground
-	EP	Exposed pad. Recommended to be connected to ground plane for best thermal conduction.

7 Specifications

7.1 Absolute Maximum Ratings⁽¹⁾

	VALUES		UNIT
	MIN	MAX	
Supply voltage, V_{CC} and V_L	−0.5	6	V
Voltage range at coax pins	−0.5	6	V
Voltage range at logic pins	−0.3	$V_L + 0.3$	V
Logic Output Current	−20	20	mA
TXOUT output current	Internally limited		
SYNCOUT output current	Internally limited		
Junction Temperature, T_J		170	°C
Storage temperature, T_{STG}	−65	150	
Continuous total power dissipation	See the Thermal Information		°C

- (1) Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

7.2 ESD Ratings

	VALUE	UNIT
$V_{(ESD)}$ Electrostatic discharge Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±2000	V

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

7.3 Thermal Information

THERMAL METRIC ⁽¹⁾		SN65HVD62	UNIT
		RGT (VQFN)	
		(16) PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	49.4	°C/W
$R_{\theta JCTop}$	Junction-to-case (top) thermal resistance	64.2	
$R_{\theta JB}$	Junction-to-board thermal resistance	22.9	
Ψ_{JT}	Junction-to-top characterization parameter	1.7	
Ψ_{JB}	Junction-to-board characterization parameter	22.9	
$R_{\theta JCbott}$	Junction-to-case (bottom) thermal resistance	25.0	

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

7.4 Recommended Operating Conditions

			MIN	NOM	MAX	UNIT
V _{CC}	Analog supply voltage		3		5.5	V
V _L	Logic supply voltage		1.6		5.5	V
V _{I(pp)}	Input signal amplitude at RXIN				1.12	V _{pp}
V _{IH}	High-level input voltage	TXIN, DIRSET1, DIRSET2	70%V _L		V _L	V
		XTAL1, XTAL2	70%V _{CC}		V _{CC}	
V _{IL}	Low-level input voltage	TXIN, DIRSET1, DIRSET2	0		30%V _L	V
		XTAL1, XTAL2	0		30%V _{CC}	
1/t _{UI}	Data signaling rate		9.6		115	kbps
F _{OSC}	Oscillator frequency	HVD62	–30 ppm	8.704	30 ppm	MHz
T _A	Operating free-air temperature		–40		105	°C
T _J	Junction Temperature		–40		125	°C
R _{LOAD}	Load impedance between TXOUT to RXIN			50		Ω
	Load impedance between RXIN and GND at f _C (channel)			50		
R1	Bias resistor between BIAS and RES			4.1		kΩ
R2	Bias resistor between RES and GND			10		kΩ
R _{SYNC}	Pull-up resistor between SYNCOUT and V _{CC}			1		kΩ
V _{RES}	Voltage at RES pin		0.7		1.5	V
C _C	Coupling capacitance between RXIN and Coax (channel)			220		nF
C _{BIAS}	Capacitance between BIAS and GND			1		μF

7.5 Electrical Characteristics

over recommended operating conditions (unless otherwise noted)

	PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
POWER SUPPLY								
100	I _{CC}	Supply current (V _{CC})	TXIN = L (Active)	DIRSET1 = L DIRSET2 = H	28	33	mA	
101			TXIN = H (Quiescent)		25	31		
102			TXIN = 115 kbps, 50% duty cycle		27	33		
99			(Standby) DIRSET1 = DIRSET2=H	12	17			
103	I _L	Logic supply current	TXIN = H, RXIN = DC input				50	μA
104	ΔV _{RXIN} / ΔV _{CC}	Receiver power supply rejection ratio	V _{TXIN} = V _L		45	60		dB
LOGIC PINS								
112	V _{OH}	High-level logic output voltage (RXOUT, DIR)	I _{OH} = −4 mA for V _L > 2.4V, I _{OH} = −2 mA for V _L < 2.4V		90%V _L			V
113	V _{OL}	Low-level logic output voltage (RXOUT, DIR)	I _{OL} = 4 mA for V _L > 2.4V, I _{OL} = 2 mA for V _L < 2.4V		10%V _L			V
114	I _{IH} /I _{IL}	Logic input current (DIRSET1/2)			−1		10	μA
	I _{IH} /I _{IL}	Logic input current (TXIN)			−2		1	μA
COAX DRIVER								
130	V _{OPP}	Peak-to-peak output voltage at device pin TXOUT (See Figure 19)	V _{RES} = 1.5 V (Maximum setting)		2.24	2.5		V _{PP}
132			V _{RES} = 0.7 V (Minimum setting)			1.17	1.3	
130A	V _{OPP}	Peak-to-peak voltage at coax out (See Figure 19)	V _{RES} = 1.5 V		5	6		dBm
132A			V _{RES} = 0.7 V			−0.6	0.3	
134	V _{OZ}	Off-state output voltage	At TXOUT				1	mVpp
134A			At coax out				−60	dBm
136		Output emissions	Coupled to coaxial cable with characteristic impedance 50 Ohms, as shown in Figure 1. With a recommended 470 pF capacitor between RXIN and GND. Measurements above 150 MHz are determined by setup.		Conforms to AISG spectrum emissions mask, 3GPP TS 25.461, see Figure 21			
41	f _o	Output frequency (HVD62)			2.176			MHz
142	Δf	Output frequency variation			−100		100	ppm
143	Z _o	Output impedance	At 100 kHz		0.03			Ω
144			At 10 MHz		3.5			Ω
145	I _{OS}	Short-circuit output current	TXOUT is also protected by a thermal shutdown circuit during short-circuit faults			300	450	mA
COAX RECEIVER								
152	V _{IT}	Input threshold	f _{IN} = 2.176 MHz		79	112	158	mVPP
152A					−18	−15	−12	dBm
154	Z _{IN}	Input impedance	f = f _O		11	21		kΩ
RECEIVER FILTER								
160	f _{PB}	Passband	VRXIN = 1.12V _{P_P}		1.1		4.17	MHz
161	f _{REJ}	Receiver rejection range	2.176MHz carrier amplitude of 112.4 mV _{PP} , Frequency band of spurious components with 800 mVPP allowed.		1.1		4.17	MHz
162	t _{noise filter}	Receiver noise filter time (slow bit rate)	DIRSET for 9.6kbps			4		μs
163		Receiver noise filter time (fast bit rate)	DIRSET for > 9.6 kbps			2		
XTAL AND SYNC								
171	I _I	Input leakage current	XTAL1, XTAL2, 0V < V _{IN} < V _{CC}		−15		15	μA
172	V _{OL}	Output low voltage	SYNCOUT, with 1 kΩ resistor from SYNCOUT to V _{CC}				0.4	V

7.6 Switching Characteristics

over recommended operating conditions (unless otherwise noted)

		PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
201	t_{pAQ}, t_{pQA}	Coax driver propagation delay	See 图 19			5	μs
202	t_r, t_f	Coax receiver output rise/fall time	$C_L = 15 \text{ pF}$, $R_L = 1 \text{ k}\Omega$, See 图 19			20	ns
203	t_{PHL}, t_{PLH}	Receiver propagation delay	See 图 20		5.5	11	μs
204	Duty Cycle	Coax receiver output duty cycle	$V_{RXIN(ON)} = 630 \text{ mVpp}$, $V_{RXIN(OFF)} < 5 \text{ mVpp}$, 50% duty cycle	40%		60%	
214			$V_{RXIN(ON)} = 200 \text{ mVpp}$, $V_{RXIN(OFF)} < 5 \text{ mVpp}$, 50% duty cycle	40%		60%	
206	t_{DIR}	Direction control active duration	DIRSET2 = DIRSET1 = GND or OPEN		1667		μs
207			DIRSET2 = GND, DIRSET1 = VL		417		
208			DIRSET2 = VL, DIRSET1 = VL		137		
209	$t_{DIR \text{ Skew}}$	Direction control skew (DIR to RXOUT)		270			ns
210	t_{DIS}	Standby disable delay	300 mV _{PP} at 2.176 MHz on RXIN		2		ms
211	t_{EN}	Standby enable delay			2		

7.7 Typical Characteristics

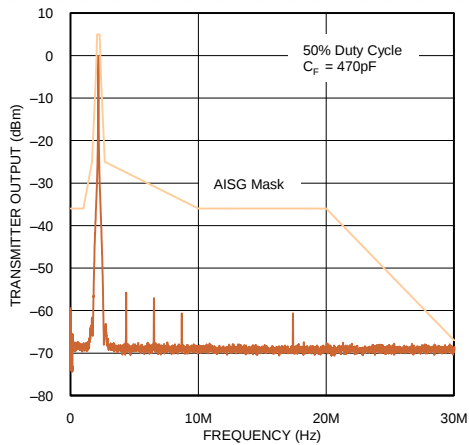


图 1. Low Frequency Emissions Spectrum with 9.6 kbps Signaling Rate

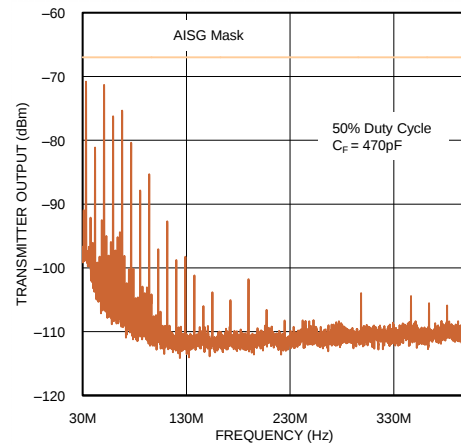


图 2. High Frequency Emissions Spectrum with 9.6 kbps Signaling Rate

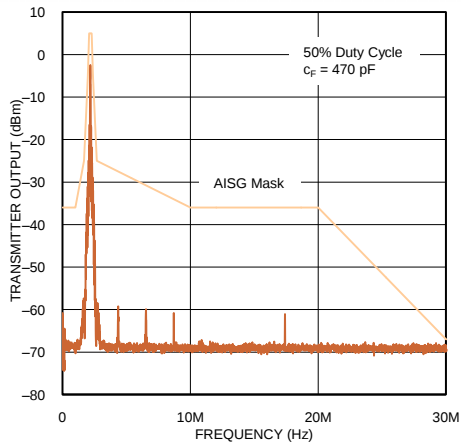


图 3. Low Frequency Emissions Spectrum with 38.4 kbps Signaling Rate

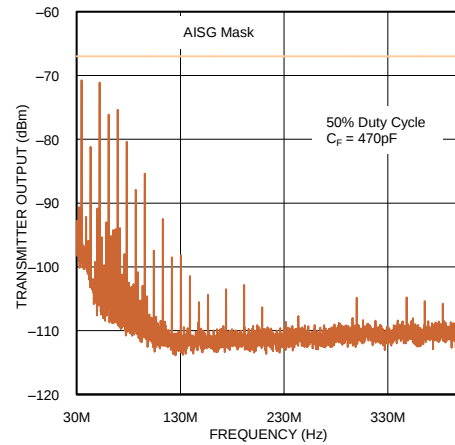


图 4. High Frequency Emissions Spectrum with 38.4 kbps Signaling Rate

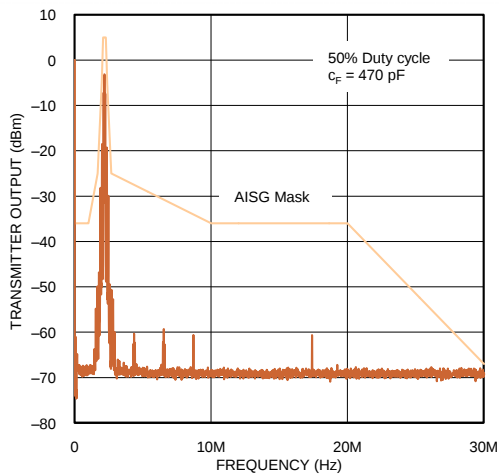


图 5. Low Frequency Emissions Spectrum with 115.2 kbps Signaling Rate

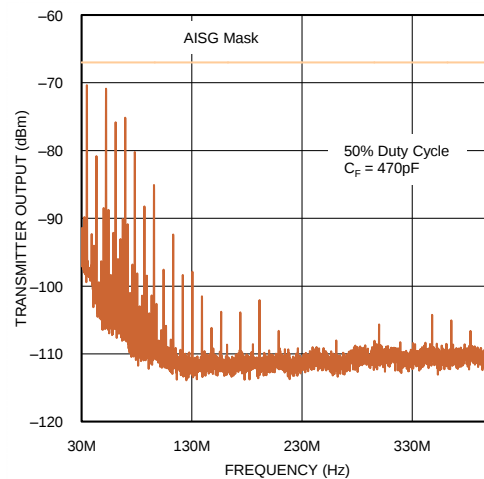


图 6. High Frequency Emissions Spectrum with 115.2 kbps Signaling Rate

Typical Characteristics (接下页)

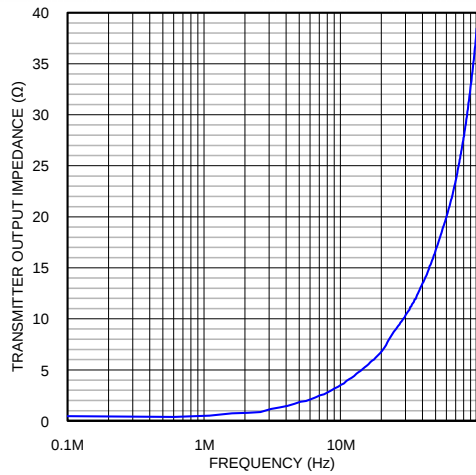


图 7. Transmitter Output Impedance

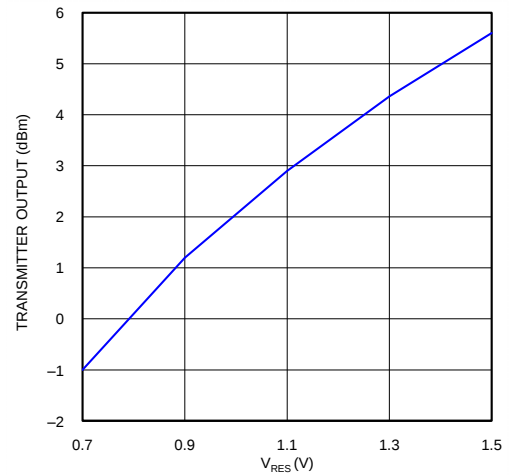


图 8. Transmit Power Adjustment

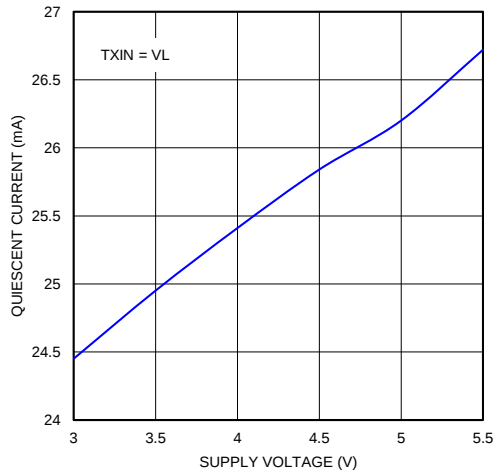


图 9. Supply Current versus Supply Voltage while Transmitting

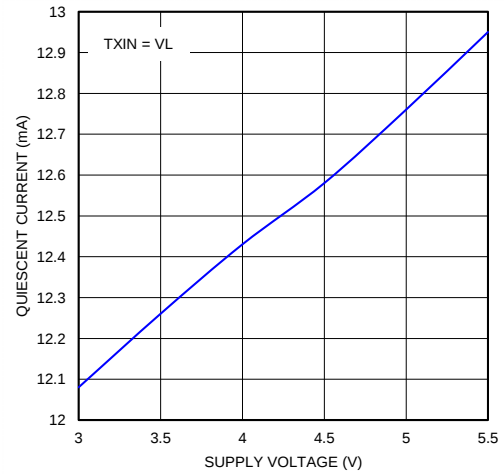


图 10. Supply Current versus Supply Voltage in Standby Mode

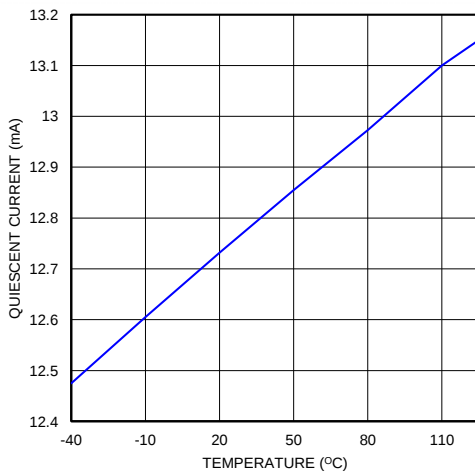


图 11. Supply Current versus Temperature in Standby Mode

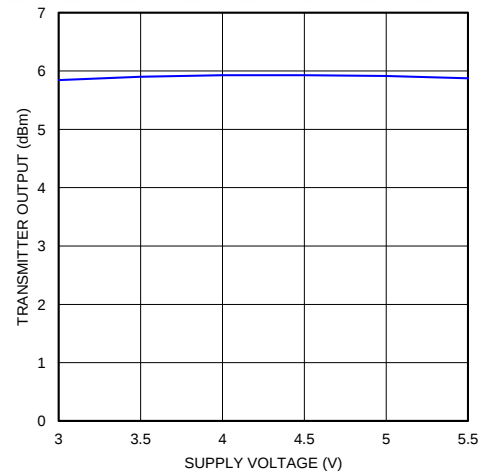


图 12. Transmitter Output Power versus Supply Voltage

Typical Characteristics (接下页)

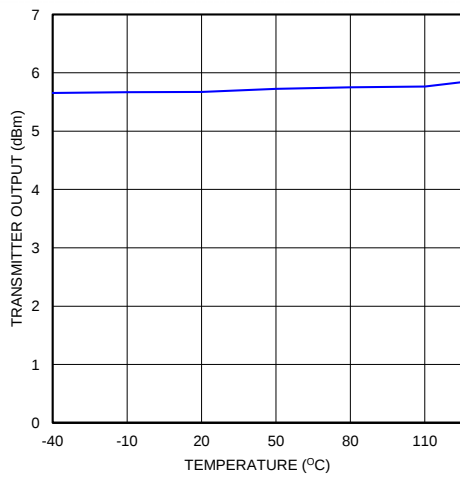


图 13. Transmitter Output Power versus Temperature

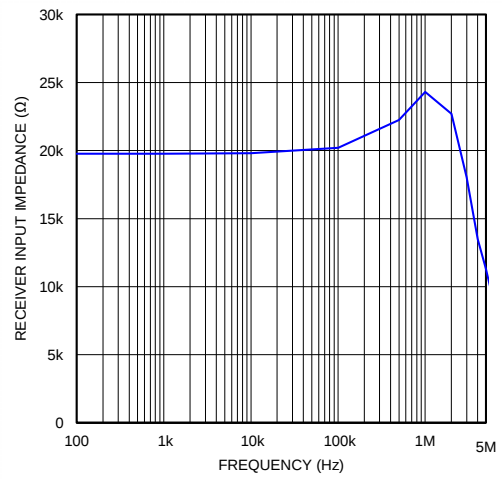


图 14. Receiver Input Impedance versus Frequency

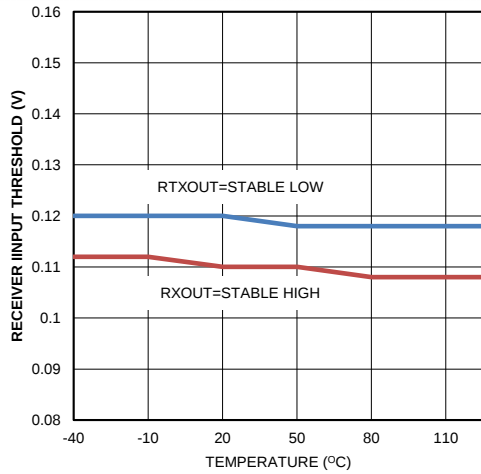


图 15. Receiver Input Threshold versus Temperature

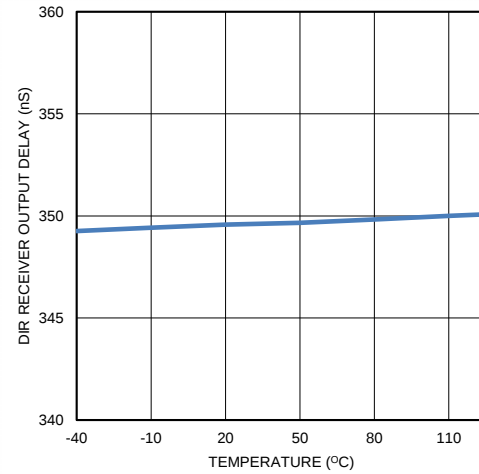


图 16. DIR Output Delay versus Temperature

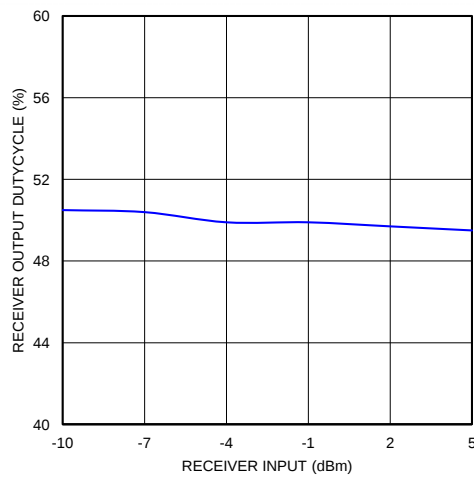


图 17. Receiver Duty Cycle with 9.6 kbps Signaling Rate

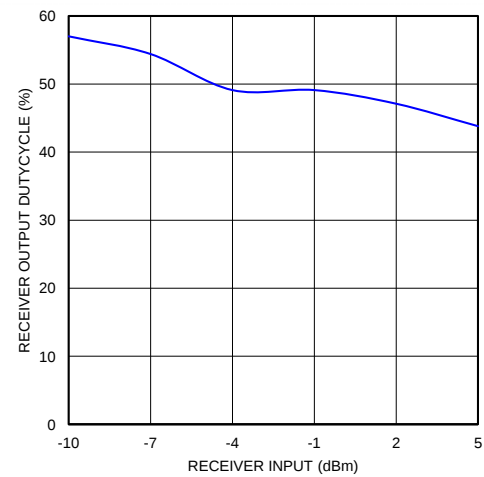


图 18. Receiver Duty Cycle with 115.2 kbps Signaling Rate

8 Parameter Measurement Information

Signal generator rate is 115 kbps, 50% duty cycle, rise and fall times less than 6 nsec, nominal output levels 0V and 3V. Coupling capacitor C_c is 220 nF.

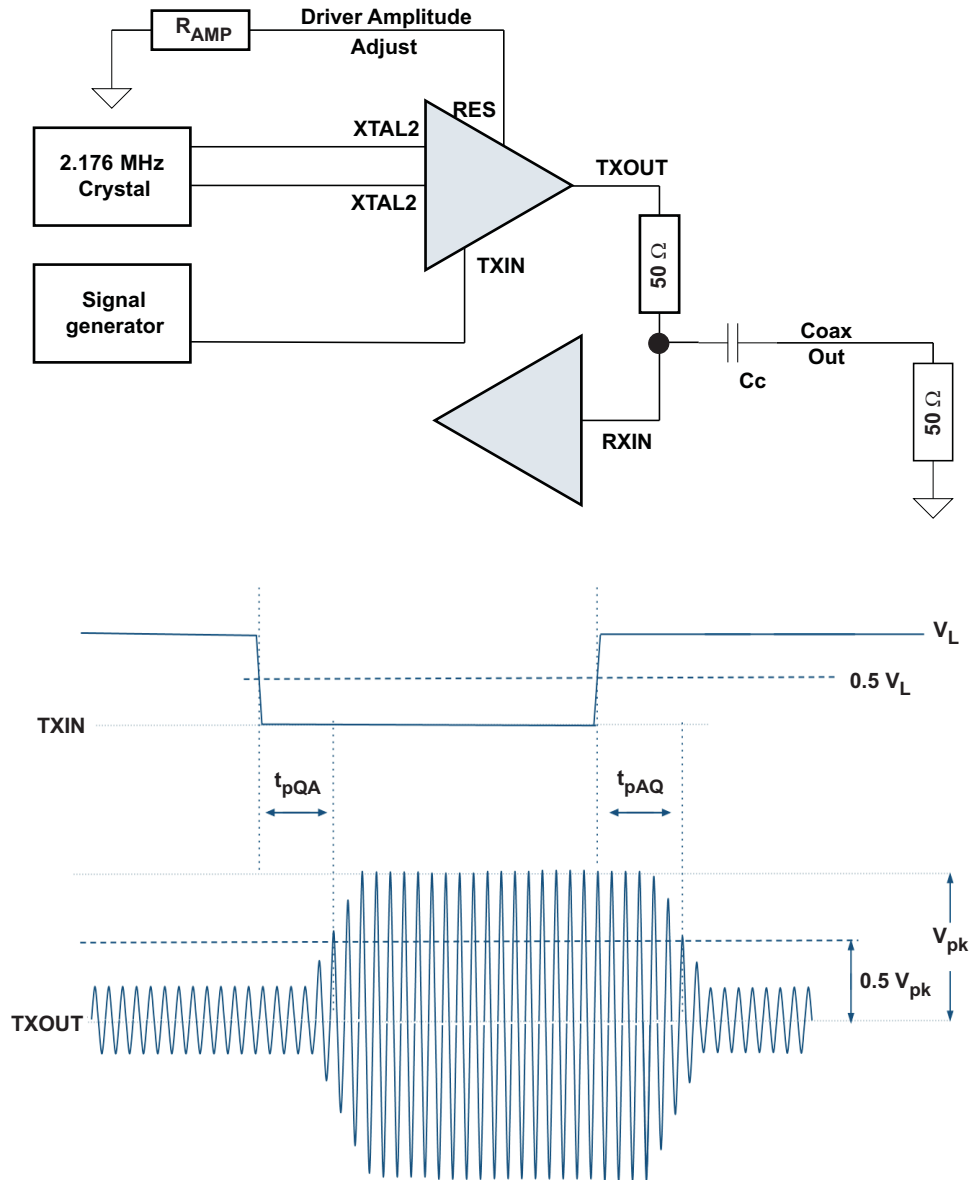


图 19. Measurement of Modem Driver Output Voltage With 50 Ω Loads

Parameter Measurement Information (接下页)

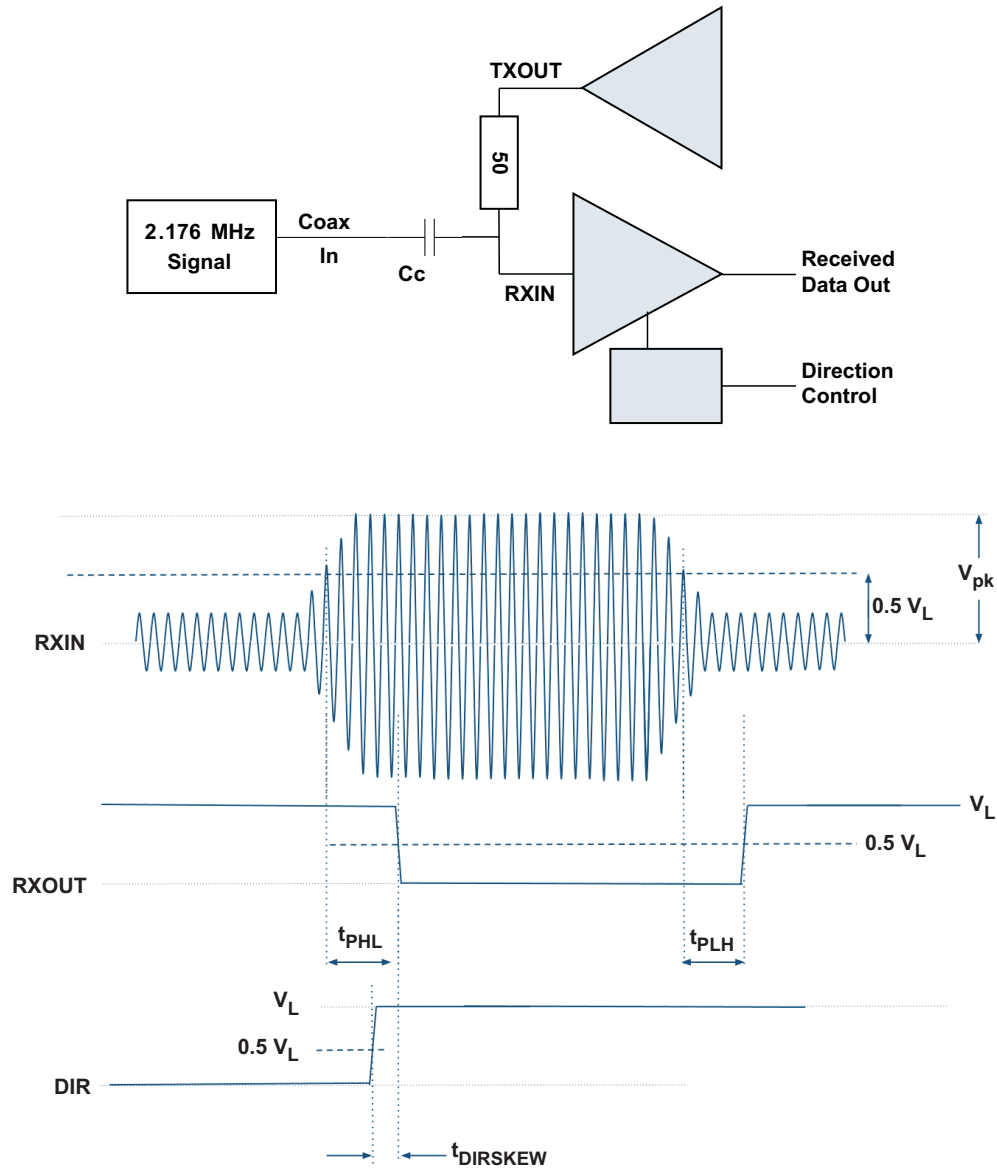


图 20. Measurement of Modem Receiver Propagation Delays

Parameter Measurement Information (接下页)

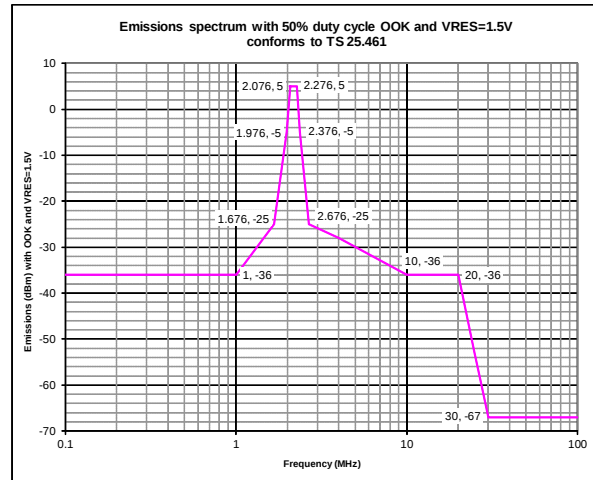


图 21. AISG Emissions Template

Device Functional Modes (接下页)

表 1. Driver Function Table⁽¹⁾

TXIN	[DIRSET1, DIRSET2]	TXOUT	COMMENT
H	[L,L], [L,H] or [H,L]	< 1 mV _{pp} at 2.176 MHz	Driver not active
L		V _{OPP} at 2.176 MHz	Driver active
X	[H,H]	< 1 mV _{pp} at 2.176 MHz	Standby mode

(1) H = High, L = Low, X = Indeterminate

表 2. Receiver and DIR Function Table⁽¹⁾

RXIN	RXOUT	DIR	COMMENT (see 图 22)
IDLE mode (not transmitting or receiving)			
< V _{IT} at 2.176 MHz for longer than DIR timeout	H	L	No outgoing or incoming signal
RECEIVE mode (not already transmitting)			
< V _{IT} at 2.176 MHz for less than t _{DIR} Timeout	H	H	Incoming '1' bit, DIR stays HIGH for DIR Timeout
> V _{IT} at 2.176 MHz for longer than t _{noise filter}	L	H	Incoming '0' bit, DIR output is HIGH
TRANSMIT mode (not already receiving)			
X	H	L	Outgoing message, DIR stays LOW for DIR Timeout

(1) H = High, L = Low

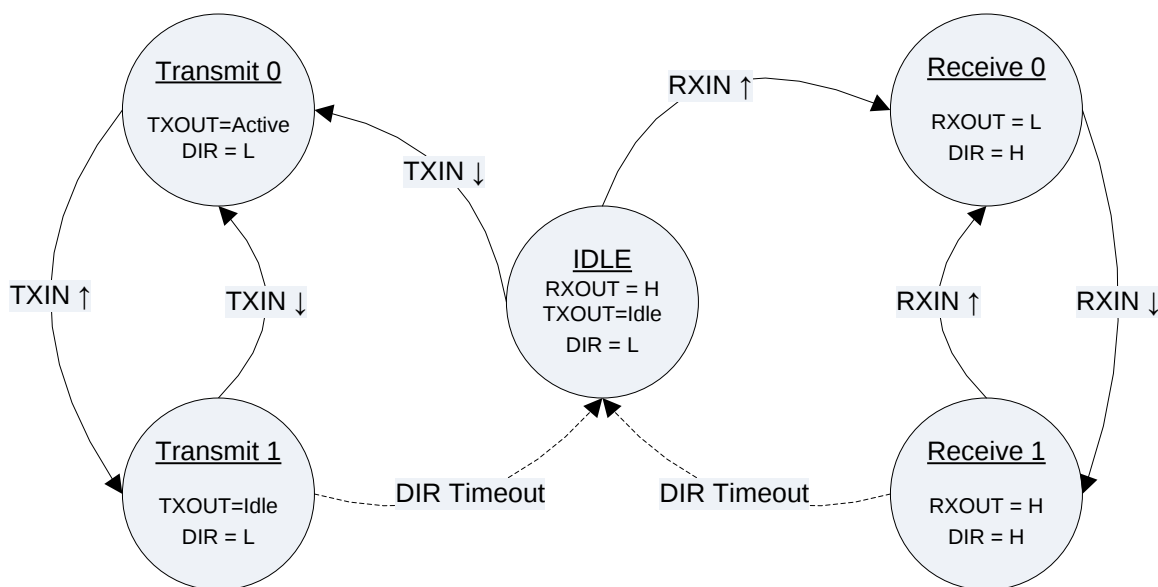


图 22. State Transition Diagram

10 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

10.1 Application Information

10.1.1 Driver Amplitude Adjust

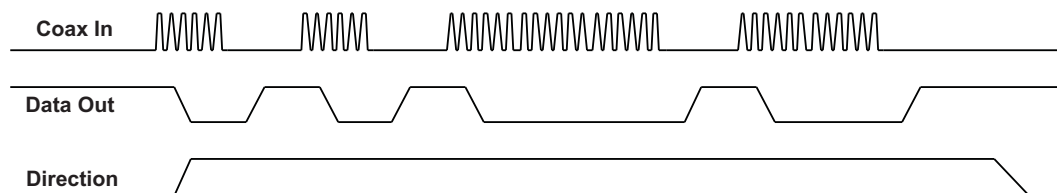
The SN65HVD62 can provide up to 2.5 V peak-to-peak of output signal at the TXOUT pin to compensate for potential loss within the external filter, cable, connections, and termination. External resistors are used to set the amplitude of the modulated driver output signal. Resistors connected across RES and BIAS set the output amplitude. The maximum peak-to-peak voltage at TXOUT is 2.5 V, corresponding to +6 dBm on the coaxial cable. The TXOUT voltage level can be adjusted by choice of resistors to set the voltage at the RES pin, according to the following equation:

$$V_{TXOUT} (V_{P-P}) = (2.5 V_{P-P} \times V_{RES} (V)) / 1.5 V_{RES} (V) = 1.5 V \times R2 / (R1 + R2) \quad V_{TXOUT} (V_{P-P}) = 2.5 V_{P-P} \times R2 / (R1 + R2). \quad (1)$$

The voltage at the RES pin should be between 0.7 V and 1.5 V. Connect RES directly to the BIAS ($R1 = 0 \Omega$) for maximum output level of 2.5 V peak-to-peak. This gives a minimum voltage level at TXOUT of 1.2 V peak-to-peak, corresponding to about 0 dBm at the coaxial cable. A 1 μ F capacitor should be connected between the BIAS pin and GND. To obtain a nominal power level of +3 dBm at the feeder cable as the AISG standard requires, use $R1 = 4.1k \Omega$ and $R2 = 10k \Omega$ that provide 1.78 V_{P-P} at TXOUT.

10.1.2 Direction Control

In many applications the mast-top modem which receives data from the base will then distribute the received data through an RS-485 network to several mast-top devices. When the mast-top modem receives the first logic 0 bit (active modulated signal) it will take control of the mast-top RS-485 network by asserting the Direction Control signal. The duration of the Direction Control assertion should be optimized to pass a complete message of length B bits at the known signaling rate ($1/t_{BIT}$) before relinquishing control of the mast-top RS-485 network. For example, if the messages are 10 bits in length ($B=10$) and the signaling rate is 9600 bits per second ($t_{BIT} = 0.104$ msec) then a positive pulse of duration 1.7 msec is sufficient (with margin to allow for network propagation delays) to enable the mast-top RS-485 drivers to distribute each received message.



10.1.3 Direction Control Time Constant

The time constant for the Direction Control function can be set by the Control Mode pins, DIRSET1/DIRSET2. These pins should be set to correspond to the desired data rate. With no external connections to the Control Mode pins, the internal time constant is set to the maximum value, corresponding to the minimum data rate.

Application Information (接下页)

10.1.4 Conversion Between dBm and Peak-to-peak Voltage

$$\text{dBm} = 20 \times \text{LOG}_{10} [\text{Volts-pp} / \text{SQRT}(0.008 \times Z_0)] = 20 \times \text{LOG}_{10} [\text{Volts-pp} / 0.63] \text{ for } Z_0 = 50 \, \Omega \quad (2)$$

$$\text{Volts-pp} = \text{SQRT}(0.008 \times Z_0) \times 10^{(\text{dBm}/20)} = 0.63 \times 10^{(\text{dBm}/20)} \text{ for } Z_0 = 50 \, \Omega \quad (3)$$

The following table shows conversions between dBm and peak-to-peak voltage with 50 Ω load, for various levels of interest including reference levels from the 3GPP TS 25.461 Technical Specification.

SIGNAL ON COAX (luant Layer 1)	dBm	Vpp (V)
Maximum Driver ON Signal	5	1.12
Nominal Driver ON Signal	3	0.89
Minimum Driver ON Signal	1	0.71
AISG Maximum Receiver Threshold	–12	0.16
Nominal Receiver Threshold	–15	0.11
Minimum Receiver Threshold	–18	0.08
Maximum Driver OFF Signal	–40	0.006

11 器件和文档支持

11.1 文档支持

11.2 商标

All trademarks are the property of their respective owners.

11.3 静电放电警告



这些装置包含有限的内置 ESD 保护。存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

11.4 术语表

[SLYZ022](#) — TI 术语表。

这份术语表列出并解释术语、首字母缩略词和定义。

12 机械、封装和可订购信息

以下页中包括机械、封装和可订购信息。 这些信息是针对指定器件可提供的最新数据。 这些数据会在无通知且不
对本文档进行修订的情况下发生改变。 欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
SN65HVD62RGTR	Active	Production	VQFN (RGT) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 105	HVD62
SN65HVD62RGTR.A	Active	Production	VQFN (RGT) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 105	HVD62
SN65HVD62RGTRG4	Active	Production	VQFN (RGT) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 105	HVD62
SN65HVD62RGTRG4.A	Active	Production	VQFN (RGT) 16	3000 LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 105	HVD62
SN65HVD62RGTT	Active	Production	VQFN (RGT) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 105	HVD62
SN65HVD62RGTT.A	Active	Production	VQFN (RGT) 16	250 SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 105	HVD62

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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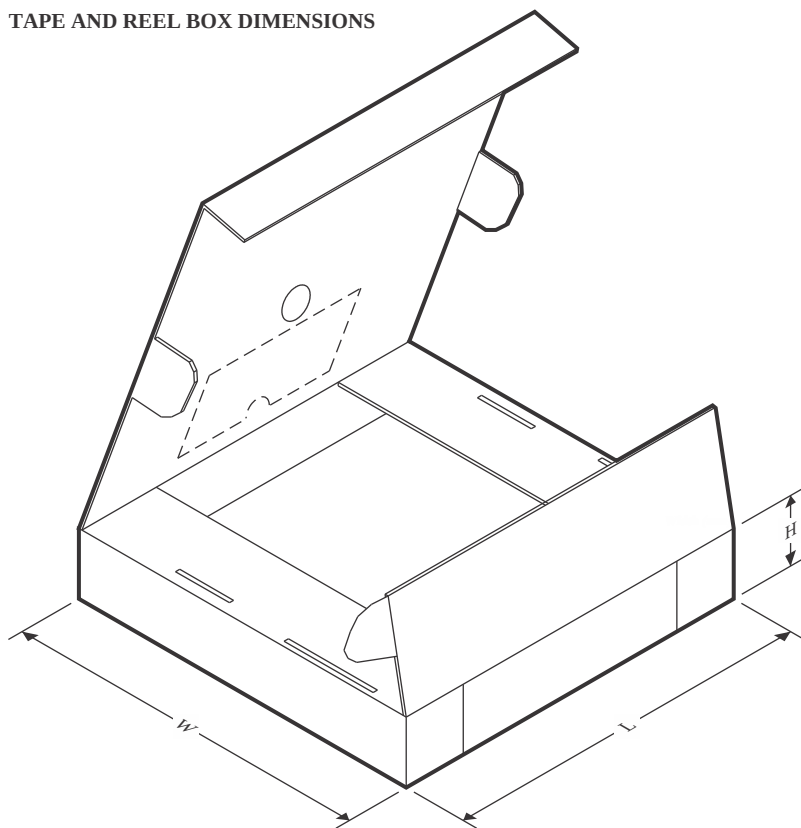
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN65HVD62RGTR	VQFN	RGT	16	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
SN65HVD62RGTRG4	VQFN	RGT	16	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
SN65HVD62RGTT	VQFN	RGT	16	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

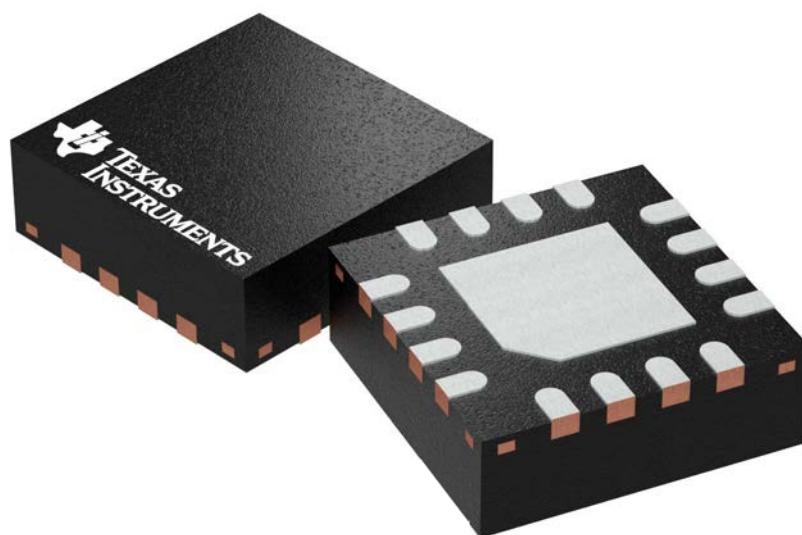
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN65HVD62RGTR	VQFN	RGT	16	3000	346.0	346.0	33.0
SN65HVD62RGTRG4	VQFN	RGT	16	3000	346.0	346.0	33.0
SN65HVD62RGTT	VQFN	RGT	16	250	210.0	185.0	35.0

RGT 16

GENERIC PACKAGE VIEW

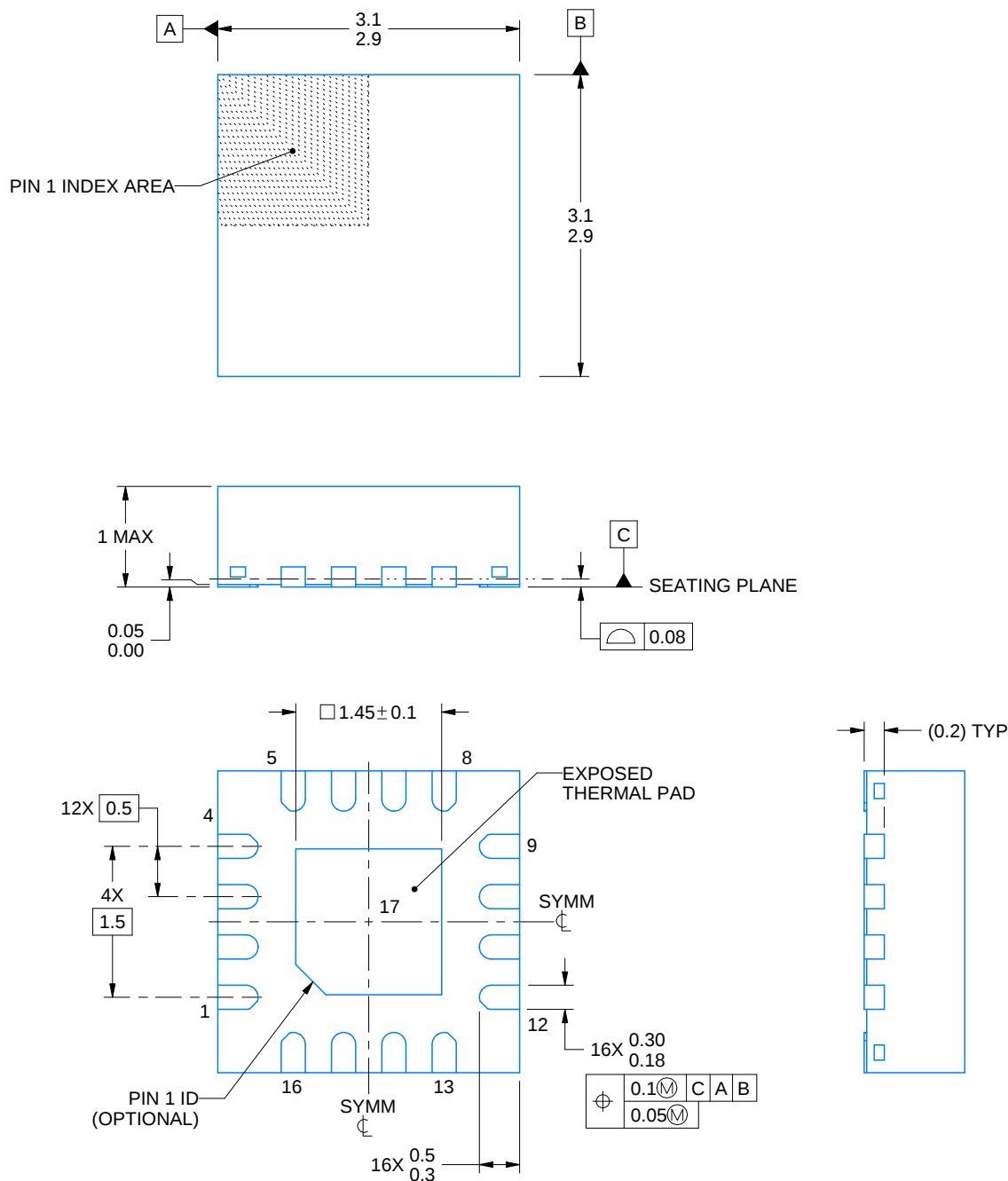
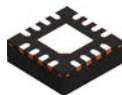
VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

4203495/1



4219032/A 02/2017

NOTES:

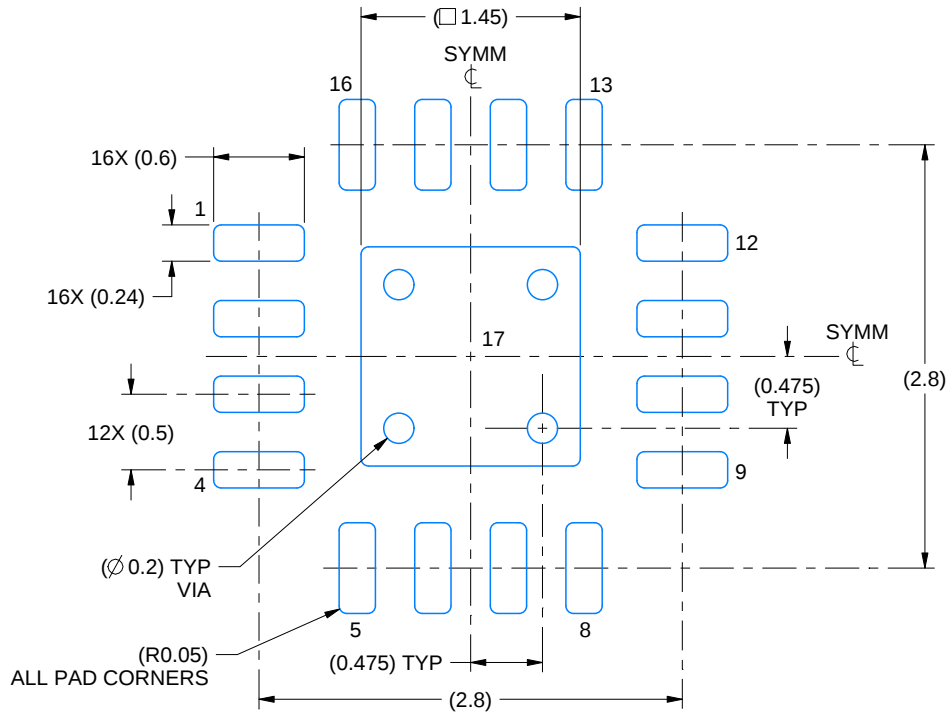
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.
4. Reference JEDEC registration MO-220

EXAMPLE BOARD LAYOUT

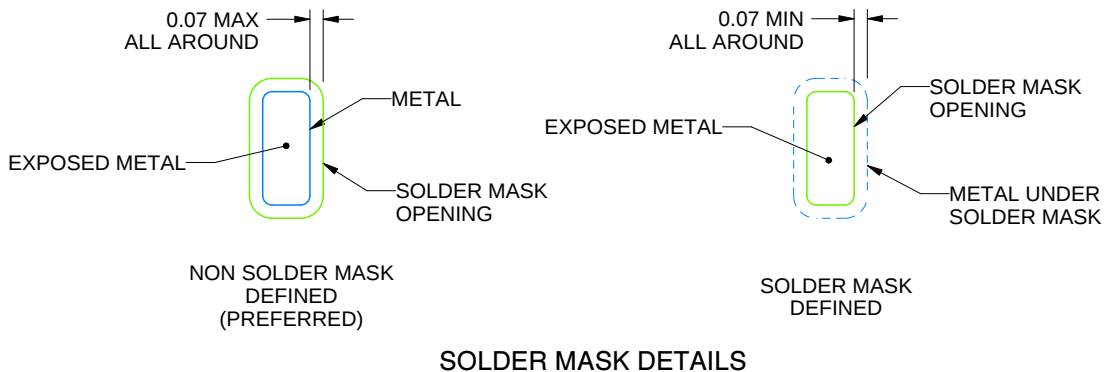
RGT0016A

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:20X



SOLDER MASK DETAILS

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NOTES: (continued)

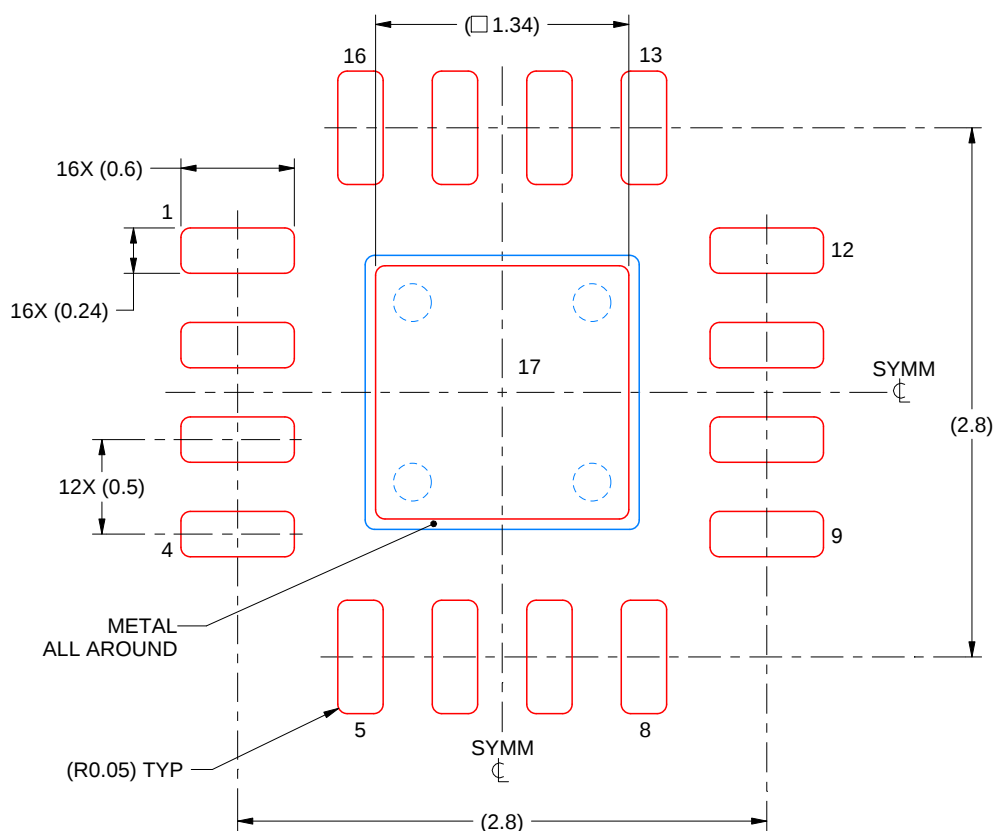
5. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
6. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

RGT0016A

VQFN - 1 mm max height

PLASTIC QUAD FLATPACK - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 17:
86% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:25X

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NOTES: (continued)

7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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